













ESD

TVS

TSS

MOV

GDT



Product specification





Features

- IEC61000-4-2 (ESD) ±8kV (Contact)
- ±15kV (Air)
- IEC61000-4-4 (EFT) 40A (5/50ŋs)
- IEC61000-4-5 (Lighting) 3A(8/20µs)
- 100 Watts Peak Pulse Power (tp=8/20µs)
- Working voltages : 24V
- Low clamping voltage
- Low leakage current

Applications

- Serial and Parallel Ports
- Notebooks, Desktops, Servers
- Projection TV
- Cellular handsets and accessories
- Portable instrumentation
- Peripherals

Mechanical Characteristics

- DFN1006 package
- Flammability Rating: UL 94V-0
- Packaging: Tape and Reel
- Reel size: 7 inch

Reference News

PACKAGE OUTLINE	Circuit Diagram	Marking
		DH
DFN1006		



ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Units
V _{ESD}	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±8 ±15	kV
P _{PP}	Peak Pulse Power (8/20µs)	150	W
Т _{орт}	Operating Temperature	-55 ~ +125	°C
T _{STG}	Storage Temperature	-55 ~ +150	°C
T _L Lead Soldering Temperature 260 (10 sec.		260 (10 sec.)	°C

ELECTRICAL CHARACTERISTICS (Tamb=25℃)

Symbol	Parameter	Test Condition	Min	Тур	Max	Units
V _{RWM}	Reverse Working Voltage				24	V
V _{BR}	Reverse Breakdown Voltage	h = 1mA	26		32	V
I _R	Reverse Leakage Current	V _{RWM} = 24V			1	μA
V _{C1}	Clamping Voltage 1	I _{PP} = 1A, t _p = 8/20µs			40	V
V _{C2}	Clamping Voltage 2	I _{PP} = 3A, t _p = 8/20µs			50	V
CJ	Junction Capacitance	$V_R = 0V, f = 1MHz$		8	15	pF



ELECTRICAL CHARACTERISTICS CURVE



Non-Repetitive Peak Pulse Power vs. Pulse Time



Pulse Waveform



PACKAGE MECHANICAL DATA



Dim	Inches		Millimeters	
Dim	MIN	MAX	MIN	МАХ
А	0.0125	0.02	0.32	0.52
В	0.000	0.002	0.00	0.05
С	0.037	0.043	0.95	1.080
D	0.022	0.027	0.55	0.680
E	0.016	0.024	0.40	0.60
F	0.008	0.012	0.20	0.30
н	0.015	БТур.	0.40	Тур.
R	0.001	0.005	0.05	0.15

Suggested Pad Layout



NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
 - CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REEL SPECIFICATION

P/N	PKG	QTY
PESD1IVN24-LSYL-MS	DF1006	10000



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